

L Number	Hits	Search Text	DB	Time stamp
1	37613	((dielectric polymer photoimageable glass sio (silicon adj2 (dioxide nitride oxynitride)) sin sion nonconfluent) with (spacer standoff))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/18 21:58
2	6040	((dielectric polymer photoimageable glass sio (silicon adj2 (dioxide nitride oxynitride)) sin sion nonconfluent) with (spacer standoff)) same (chip dice die semiconductor (integrated adj circuit) ic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/18 22:00
3	1022	((dielectric polymer photoimageable glass sio (silicon adj2 (dioxide nitride oxynitride)) sin sion nonconfluent) with (spacer standoff)) same (chip dice die semiconductor (integrated adj circuit) ic) same (stack stacking stacked multi multiple level multichip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/18 22:02